# **KY DMLS31.23**

### SYNIOS® P2720

This compact LED device is part of the SYNIOS P2720 family. Given the scalability of this product family, it provides full performance and flexibility with just one footprint.

The KY DMLS31.23 product is meant to provide superior light quality in 1 mm<sup>2</sup> chip size class.



### **Applications**

- Interior Illumination (e.g. Ambient Map)

- Signalling

### **Features:**

- Package: SMD epoxy package
- Chip technology: Thinfilm
- Typ. Radiation: 120° (Lambertian emitter)
- Color:  $\lambda_{dom} = 590 \text{ nm} (\circ \text{ yellow})$
- Corrosion Robustness Class: 3B
- Qualifications: AEC-Q102 Qualified with RV-level 1
- ESD: 2 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)





# **Ordering Information**

Туре	Luminous Flux <sup>1)</sup> I <sub>F</sub> = 700 mA Φ <sub>v</sub>	Ordering Code
KY DMLS31.23-8H7K-35-M3W3	40 100 lm	Q65112A8814
KY DMLS31.23-8J7L-46-M3W3	63 159 lm	Q65112A0161



# **Maximum Ratings**

Parameter	Symbol		Values
Operating Temperature	T <sub>op</sub>	min.	-40 °C
		max.	125 °C
Storage Temperature	T <sub>stg</sub>	min.	-40 °C
		max.	125 °C
Junction Temperature	T <sub>j</sub>	max.	150 °C
Junction Temperature for short time applications*	T <sub>j</sub>	max.	175 °C
Forward current	I <sub>F</sub>	min.	20 mA
T <sub>s</sub> = 25 °C		max.	1000 mA
Surge Current t ≤ 10 μs; D = 0.005 ; T <sub>s</sub> = 25 °C	Ι <sub>FS</sub>	max.	2500 mA
Reverse voltage <sup>2)</sup> T <sub>s</sub> = 25 °C	V <sub>R</sub>	max.	12 V
ESD withstand voltage acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)	$V_{ESD}$		2 kV

\* The median lifetime (L70/B50) for Tj =  $175^{\circ}$ C is 100h.



### **Characteristics**

 $I_{_{
m F}}$  = 700 mA;  $T_{_{
m S}}$  = 25 °C

Parameter	Symbol	Symbol		
Peak Wavelength	$\lambda_{peak}$	typ.	593 nm	
Dominant Wavelength <sup>3)</sup>	λ <sub>dom</sub>	min.	583 nm	
I <sub>E</sub> = 700 mA	dom	typ.	590 nm	
		max.	595 nm	
Spectral Bandwidth at 50% I <sub>rel,max</sub>	Δλ	typ.	18 nm	
Viewing angle at 50% ${\rm I_v}$	2φ	typ.	120 °	
Forward Voltage 4)	V <sub>F</sub>	min.	2.15 V	
I <sub>F</sub> = 700 mA		typ.	2.55 V	
		max.	2.75 V	
Reverse current <sup>2)</sup>	I <sub>R</sub>	typ.	0.01 µA	
$V_R = 12 V$	ix is a second s	max.	10 µA	
Real thermal resistance junction/solderpoint <sup>5</sup> )	$R_{thJS real}$	typ.	9.0 K / W	
	noordu	max.	11.5 K / W	
Electrical thermal resistance junction/solderpoint <sup>5)</sup>	R <sub>thJS elec.</sub>	typ.	7.7 K / W	
with efficiency $\eta_e$ = 15 %		max.	9.8 K / W	

# **Brightness Groups**

Group	Luminous Flux <sup>1)</sup> I <sub>F</sub> = 700 mA min. $\Phi_v$	Luminous Flux <sup>1)</sup> I <sub>F</sub> = 700 mA max. Φ <sub>v</sub>	Luminous Intensity <sup>6)</sup> I <sub>F</sub> = 700 mA typ. I <sub>v</sub>
8H	40 lm	45 lm	14 cd
5J	45 lm	50 lm	16 cd
6J	50 lm	56 lm	18 cd
7J	56 lm	63 lm	20 cd
8J	63 lm	71 lm	22 cd
5K	71 lm	80 lm	25 cd
6K	80 lm	90 lm	28 cd
7K	90 lm	100 lm	31 cd
8K	100 lm	112 lm	35 cd
5L	112 lm	125 lm	39 cd
6L	125 lm	140 lm	44 cd
7L	140 lm	159 lm	49 cd

# Forward Voltage Groups

Group	Forward Voltage <sup>4)</sup> I <sub>F</sub> = 700 mA min. V <sub>F</sub>	Forward Voltage <sup>4)</sup> I <sub>F</sub> = 700 mA max. V <sub>F</sub>	
M3	2.15 V	2.30 V	
Q3	2.30 V	2.45 V	
Т3	2.45 V	2.60 V	
W3	2.60 V	2.75 V	



# Wavelength Groups

Group	Dominant Wavelength <sup>3)</sup> I <sub>F</sub> = 700 mA min. λ <sub>dom</sub>	Dominant Wavelength <sup>3)</sup> I <sub>F</sub> = 700 mA max. $\lambda_{dom}$
3	583 nm	586 nm
4	586 nm	589 nm
5	589 nm	592 nm
6	592 nm	595 nm

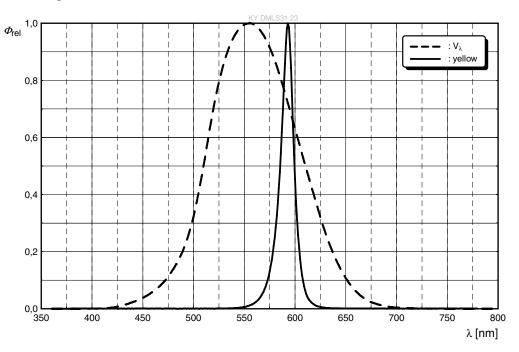


# Group Name on Label

Example: 5J-3-M3 Brightness	Wavelength	Forward Voltage
5J	3	M3

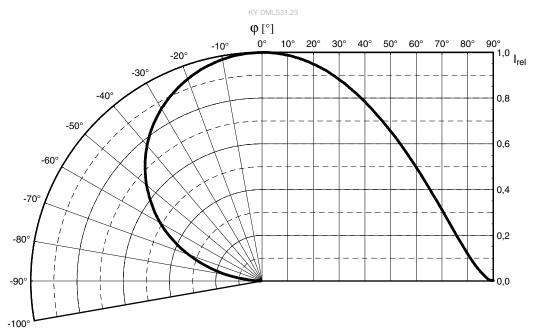
### **Relative Spectral Emission**<sup>6)</sup>

 $\Phi_{_{rel}}$  = f ( $\lambda$ ); I $_{_F}$  = 700 mA; T $_{_S}$  = 25 °C



### **Radiation Characteristics**<sup>6)</sup>

 $I_{rel} = f(\phi); T_{s} = 25 \ ^{\circ}C$ 



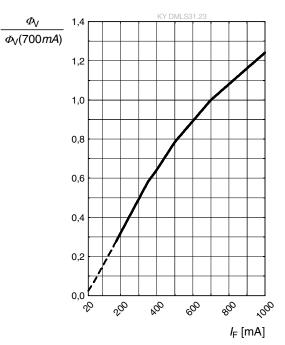


Forward current <sup>6), 7)</sup>

# $I_{F} = f(V_{F}); T_{S} = 25 °C$ $I_{F} [mA] 1000 F(V DMLS31.23) F(V DMLS31.23)$

### Relative Luminous Flux <sup>6), 7)</sup>

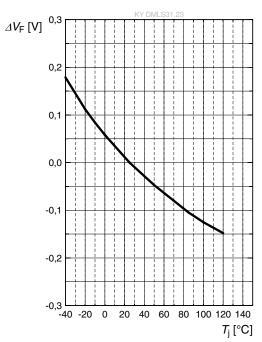
 $\Phi_{v}/\Phi_{v}(700 \text{ mA}) = f(I_{F}); T_{S} = 25 \text{ °C}$ 





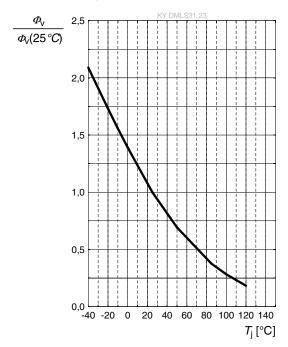
# Forward Voltage <sup>6)</sup>

 $\Delta V_{_F} = V_{_F} - V_{_F}(25 \text{ °C}) = f(T_{_J}); I_{_F} = 700 \text{ mA}$ 



### **Relative Luminous Flux**<sup>6)</sup>

 $\Phi_v/\Phi_v(25 \text{ °C}) = f(T_i); I_F = 700 \text{ mA}$ 



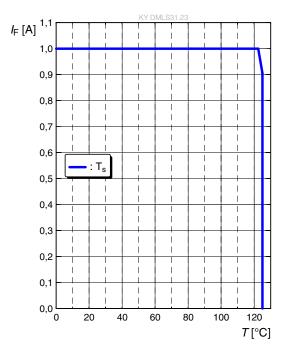
### **Dominant Wavelength**<sup>6)</sup>

 $\Delta \lambda_{dom} = \lambda_{dom} - \lambda_{dom} (25 \text{ °C}) = f(T_j); I_F = 700 \text{ mA}$   $\Delta \lambda_{dom} [nm] \xrightarrow{0}{} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1} 10^{-1}$ 



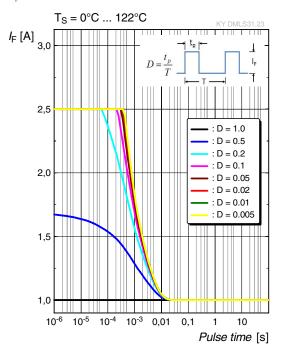
### Max. Permissible Forward Current

 $I_{F} = f(T)$ 



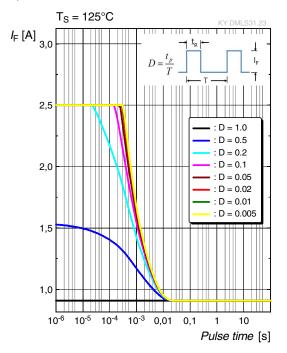
### Permissible Pulse Handling Capability

 $I_{F} = f(t_{p}); D: Duty cycle$ 



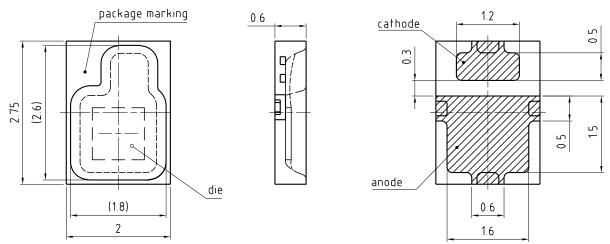
# Permissible Pulse Handling Capability

 $I_{F} = f(t_{p}); D: Duty cycle$ 





### **Dimensional Drawing**<sup>8)</sup>



General tolerance	±0.1
Lead finish Au	

Further Information:

Approximate Weight: 12.0 mg

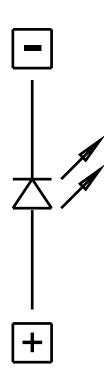
**Corrosion test:** 

Class: 3B Test condition: 40°C / 90 % RH / 15 ppm  $\rm H_2S$  / 14 days (stricter than IEC 60068-2-43)

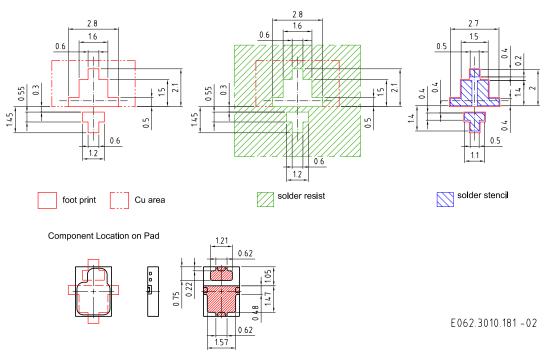
OSRAM Opto Semiconductors

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## **Electrical Internal Circuit**



### **Recommended Solder Pad**<sup>8)</sup>

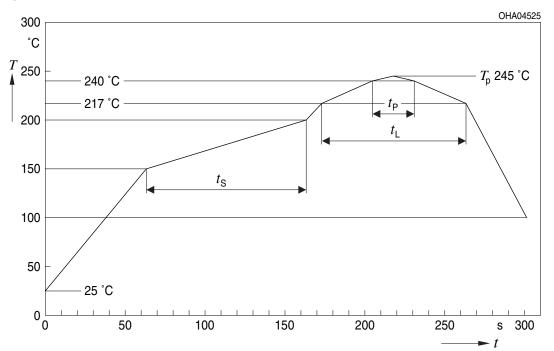


For superior solder joint connectivity results we recommend soldering under standard nitrogen atmosphere. Package not suitable for ultra sonic cleaning.



### **Reflow Soldering Profile**

Product complies to MSL Level 2 acc. to JEDEC J-STD-020E



Profile Feature	Symbol	Pb	Pb-Free (SnAgCu) Assembly		
		Minimum	Recommendation	Maximum	
Ramp-up rate to preheat <sup>*)</sup> 25 °C to 150 °C			2	3	K/s
Time t <sub>s</sub> T <sub>smin</sub> to T <sub>smax</sub>	t <sub>s</sub>	60	100	120	S
Ramp-up rate to peak <sup>*)</sup> $T_{smax}$ to $T_{p}$			2	3	K/s
Liquidus temperature	TL		217		°C
Time above liquidus temperature	t		80	100	S
Peak temperature	Τ <sub>Ρ</sub>		245	260	°C
Time within 5 °C of the specified peak temperature $T_p$ - 5 K	t <sub>P</sub>	10	20	30	S
Ramp-down rate* T <sub>P</sub> to 100 °C			3	6	K/s
Time 25 °C to T <sub>P</sub>				480	S

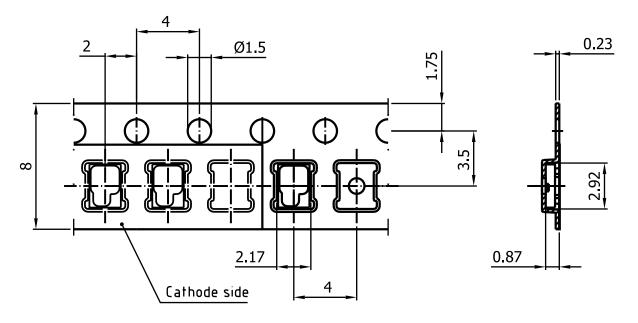
All temperatures refer to the center of the package, measured on the top of the component

\* slope calculation DT/Dt: Dt max. 5 s; fulfillment for the whole T-range



### KY DMLS31.23

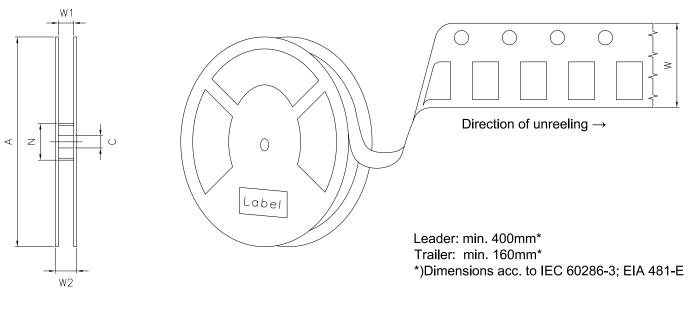
Taping<sup>8)</sup>



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### Tape and Reel <sup>9)</sup>

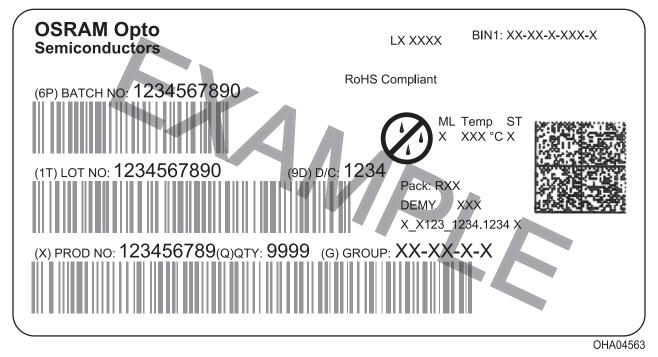


### **Reel Dimensions**

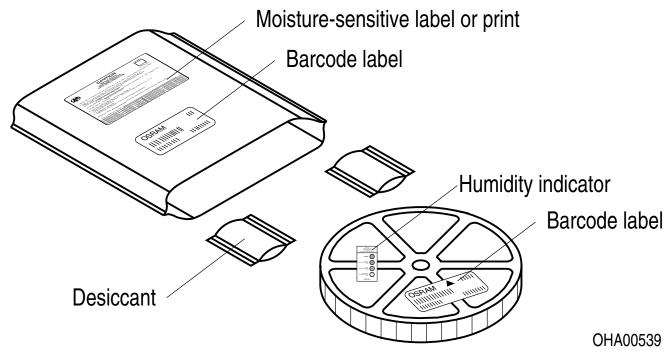
А	W	N <sub>min</sub>	W <sub>1</sub>	$W_{2 \max}$	Pieces per PU
180 mm	8 + 0.3 / - 0.1 mm	60 mm	8.4 + 2 mm	14.4 mm	2000



### **Barcode-Product-Label (BPL)**



### Dry Packing Process and Materials<sup>8)</sup>



Moisture-sensitive product is packed in a dry bag containing desiccant and a humidity card according JEDEC-STD-033.



### Notes

The evaluation of eye safety occurs according to the standard IEC 62471:2006 (photo biological safety of lamps and lamp systems). Within the risk grouping system of this IEC standard, the device specified in this data sheet fall into the class **exempt group (exposure time 10000 s)**. Under real circumstances (for exposure time, conditions of the eye pupils, observation distance), it is assumed that no endangerment to the eye exists from these devices. As a matter of principle, however, it should be mentioned that intense light sources have a high secondary exposure potential due to their blinding effect. When looking at bright light sources (e.g. headlights), temporary reduction in visual acuity and afterimages can occur, leading to irritation, annoyance, visual impairment, and even accidents, depending on the situation.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

For further application related information please visit www.osram-os.com/appnotes



### Disclaimer

### Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on the OSRAM OS website.

### Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

### Product and functional safety devices/applications or medical devices/applications

OSRAM OS components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

OSRAM OS products are not qualified at module and system level for such application.

In case buyer – or customer supplied by buyer – considers using OSRAM OS components in product safety devices/applications or medical devices/applications, buyer and/or customer has to inform the local sales partner of OSRAM OS immediately and OSRAM OS and buyer and /or customer will analyze and coordinate the customer-specific request between OSRAM OS and buyer and/or customer.



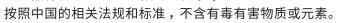
### Glossary

- <sup>1)</sup> **Brightness:** Brightness values are measured during a current pulse of typically 25 ms, with an internal reproducibility of  $\pm 8$  % and an expanded uncertainty of  $\pm 11$  % (acc. to GUM with a coverage factor of k = 3).
- <sup>2)</sup> **Reverse Operation:** This product is intended to be operated applying a forward current within the specified range. Applying any continuous reverse bias or forward bias below the voltage range of light emission shall be avoided because it may cause migration which can change the electro-optical characteristics or damage the LED.
- <sup>3)</sup> **Wavelength:** The wavelength is measured at a current pulse of typically 25 ms, with an internal reproducibility of ±0.5 nm and an expanded uncertainty of ±1 nm (acc. to GUM with a coverage factor of k = 3).
- <sup>4)</sup> **Forward Voltage:** The forward voltage is measured during a current pulse of typically 8 ms, with an internal reproducibility of  $\pm 0.05$  V and an expanded uncertainty of  $\pm 0.1$  V (acc. to GUM with a coverage factor of k = 3).
- <sup>5)</sup> **Thermal Resistance:** Rth max is based on statistic values ( $6\sigma$ ).
- <sup>6)</sup> **Typical Values:** Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- <sup>7)</sup> **Characteristic curve:** In the range where the line of the graph is broken, you must expect higher differences between single devices within one packing unit.
- <sup>8)</sup> **Tolerance of Measure:** Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.
- <sup>9)</sup> **Tape and Reel:** All dimensions and tolerances are specified acc. IEC 60286-3 and specified in mm.



Revision History			
Version	Date	Change	
1.4	2019-07-24	Ordering Information Characteristics Brightness Groups Wavelength Groups	
1.5	2021-02-18	Features Schematic Transportation Box Dimensions of Transportation Box Glossary	





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单击下面可查看定价,库存,交付和生命周期等信息

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